

30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

300mA

Features

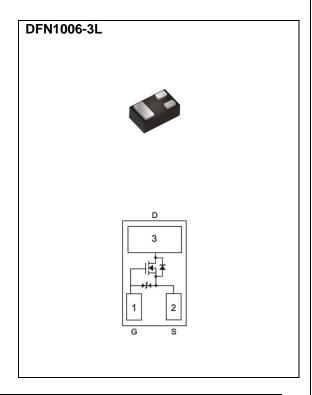
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Switch Load
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN1006-3L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0007 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V_{DS}	30	- v	
Gate-Source Voltage		V_{GS}	±10		
Continuous Drain Current(Note 4)		I _D	300	mA	
Pulsed Drain Current ^(Note 1)		I _{DM}	600		
Power Dissipation	T _A =25°C	Po	700	mW	
	Derate above 25°C		5.6	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient ^(Note 5)		R _{θJA}	175	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	0.4	0.75	1.0	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V,I _D =300mA	-	0.7	1.2	Ω
		V _{GS} =2.5V,I _D =200mA	-	0.8	1.6	
		V _{GS} =1.8V,I _D =100mA	-	0.9	2.0	
		V _{GS} =1.5V,I _D =50mA	-	1.1	3.0	
		V _{GS} =1.2V,I _D =20mA		1.5	4.0	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =24V, V _{GS} =0V - V _{GS} =±8V, V _{DS} =0V -	-	1		
Gate-Source Leakage Current	I _{GSS}		-	-	±10	uA
Dynamic ^(Note 6)						
Total Gate Charge	Qg	V _{DS} =10V, I _D =300mA, V _{GS} =4.5V	-	0.9	-	nC
Gate-Source Charge	Q _{gs}		-	0.3	-	
Gate-Drain Charge	Q_{gd}	VGS=4.5 V	-	0.2	-	
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, f=1.0MHZ	-	45	-	
Output Capacitance	Coss		-	14	-	pF
Reverse Transfer Capacitance	Crss	I=1.UIVIDZ	-	0.8	-	
Turn-On Delay Time	td _(on)	V_{DD} =10V, I_{D} =300mA, V_{GS} =4V, R_{G} =10 Ω (Note 1,2)	-	8.3	-	
Turn-On Rise Time	tr		-	5.7	-	ns
Turn-Off Delay Time	td(off)		-	35	-	
Turn-Off Fall Time	tf	NG=1022(1888 1,2)	-	12	-	
Drain-Source Diode						
Diode Forward Current	Is		-	-	300	mA
Diode Forward Voltage	V _{SD}	Is=300mA, V _{GS} =0V	-	0.9	1.3	V

Notes:

- 1.Pulse width<300us, Duty cycle<2%.
- $\hbox{2.Essentially independent of operating temperature typical characteristics.}\\$
- 3.Repetitive rating, pulse width limited by junction temperature T_J(MAX)=150°C.Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4.Reua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5.Guaranteed by design, not subject to production testing.



2.5

2.0

1.5

1.0

0.5

V_{GS}= 1.2V

 $R_{DS}(on)$ - On-Resistance (Ω)

TYPICAL CHARACTERISTIC CURVES

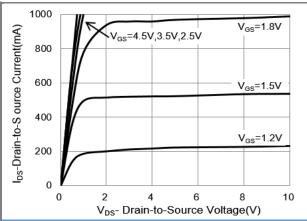
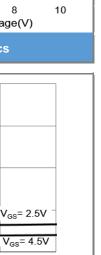


Fig.1 Output Characteristics



200

0

0

Fig.3 On-Resistance vs. Drain Current

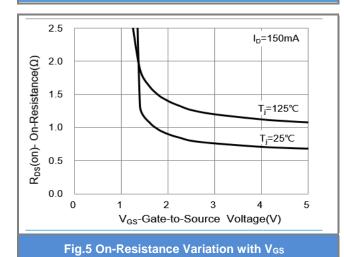
100

V_{GS}= 1.5V = 1.8V

200

I_{DS}-Drain-to-Source Current(mA)

300



1000 V_{DS}=5V los-Drain-to-S ource Current(mA) 800 600 400

Fig.2 Transfer Characteristics

1.2

V_{GS}-Gate-to-Source Voltage(V)

T_J=125℃

0.6

T_J=25℃

2.4

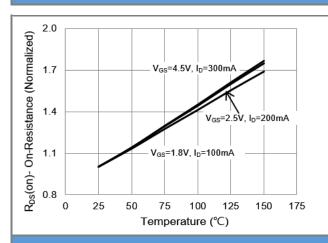


Fig.4 On-Resistance vs. Junction temperature

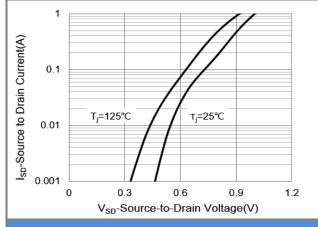


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

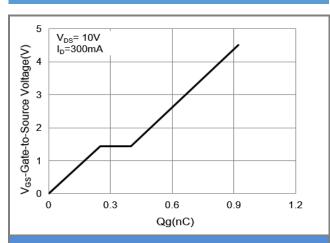


Fig.7 Gate-Charge Characteristics

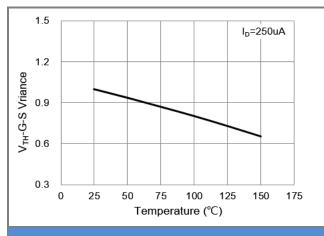


Fig.9 Threshold Voltage Variation with Temperature

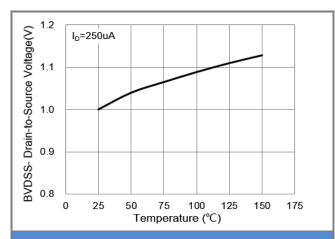


Fig.8 Breakdown Voltage Variation vs. Temperature

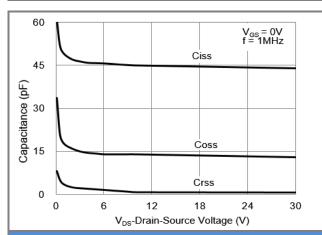


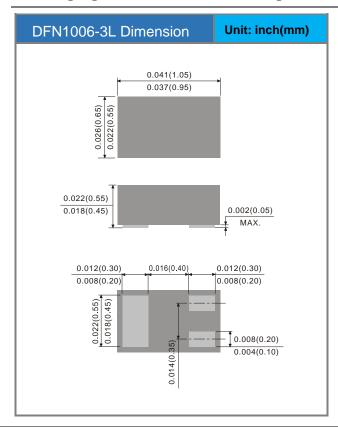
Fig.10 Capacitance vs. Drain-Source Voltage

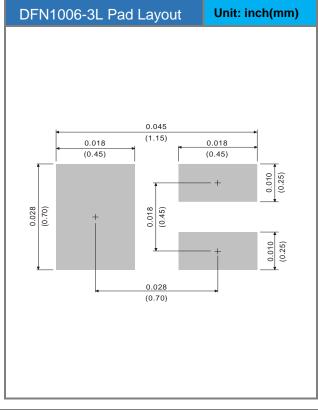


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ1906	DFN1006-3L	10K pcs / 7" reel	6

Packaging Information & Mounting Pad Layout







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